



Automotive ultrafast recovery diode

Datasheet - production data

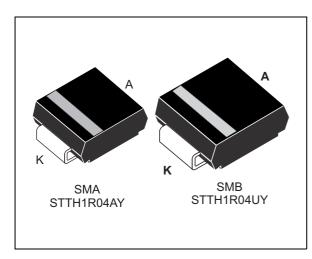


Table 1. Device summary

Symbol	Value
I _{F(AV)}	1 A
V_{RRM}	400 V
T _{j (max)}	175 °C
V _{F (typ)}	0.9 V
t _{rr (typ)}	14 ns

Features

- Negligible switching losses
- Low forward and reverse recovery times
- High junction temperature
- AEC-Q101 qualified
- ECOPACK®2 compliant component

Description

The STTH1R04-Y series uses ST's new 400 V planar Pt doping technology. Specially suited for switching mode base drive and transistor circuits.

Packaged in surface mount packages, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection for all automotive application. Characteristics STTH1R04-Y

Characteristics 1

Table 2. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Paramet		Value	Unit	
V_{RRM}	Repetitive peak reverse voltage	400	V		
1	Average forward current, $\delta = 0.5$	SMA	T _{lead} = 130 °C	1.0	А
I _{F(AV)}	SMB	SMB	T _{lead} = 140 °C	1.0	
I _{FSM}	Surge non repetitive forward current	30	Α		
T _{stg}	Storage temperature range	-65 to +175	°C		
T _j	Operating junction temperature ⁽¹⁾			-40 to 175	°C

^{1.} On infinite heatsink with 10 mm lead length

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit	
D	Junction to lead	SMA	30	°C/W
R _{th(j-l)}	Junction to lead	SMB	25	C/VV

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min	Тур	Max	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V- - V			5	μA
'R`	TRY Reverse leakage current	T _j = 125 °C	$V_R = V_{RRM}$		5	50	μΑ
		T _j = 25 °C				1.6	
V _F ⁽²⁾	V _F ⁽²⁾ Forward voltage drop	T _j = 100 °C	I _F = 1.0 A		1.05	1.3	V
		T _j = 150 °C			0.9	1.15	

^{1.} Pulse test: t_p = 5 ms, δ < 2 %

To evaluate the conduction losses use the following equation: P = 0.9 x $I_{F(AV)}$ + 0.250 x $I_{F}^2_{(RMS)}$

$$P = 0.9 \text{ x } I_{F(AV)} + 0.250 \text{ x } I_{F(RMS)}^2$$

^{2.} Pulse test: t_p = 380 μ s, δ < 2 %

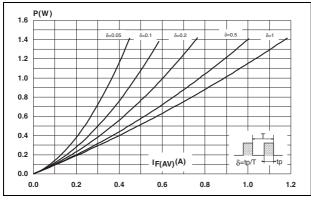
STTH1R04-Y Characteristics

Table 5. Dynamic characteristics

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
	Royarga racovary tima	$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$			30	ns
t _{rr} Reverse recovery time	$I_F = 1 \text{ A, } dI_F/dt = -100 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$		14	20	115	
I _{RM}	Reverse recovery current	$I_F = 1 \text{ A, } dI_F/dt = -200 \text{ A/µs,}$ $V_R = 320 \text{ V, } T_j = 125 \text{ °C}$		2.5	3.5	Α
t _{fr}	Forward recovery time	$I_F = 1 \text{ A}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}, T_j = 25 \text{ °C}$			50	ns
V _{FP}	Forward recovery voltage	$I_F = 1 \text{ A, } dI_F/dt = 100 \text{ A/}\mu\text{s, } T_j = 25 ^{\circ}\text{C}$		2.9		V

Figure 1. Conduction losses versus average forward current

Figure 2. Forward voltage drop versus forward current



100.0

T_{.j=150°C}
(Maximum values)

1.0

T_{.j=150°C}
(Typical values)

V_{FM}(V)

0.1

0.0

0.4

0.8

1.2

1.6

2.0

2.4

2.8

3.2

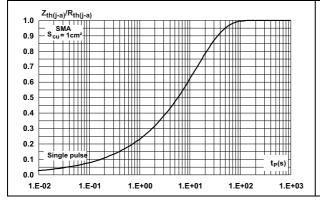
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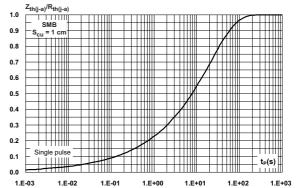
4.0

4.4

Figure 3. Relative variation of thermal impedance junction to ambient versus pulse duration, SMA

Figure 4. Relative variation of thermal impedance junction to ambient versus pulse duration, SMB





Characteristics STTH1R04-Y

Figure 5. Junction capacitance versus reverse voltage applied (typical values)

Figure 6. Reverse recovery charges versus dl_F/dt (typical values)

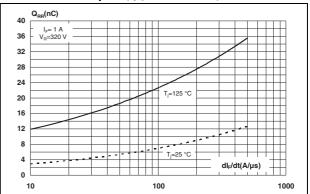


Figure 7. Reverse recovery time versus dl_F/dt (typical values)

Figure 8. Peak reverse recovery current versus dI_F/dt (typical values)

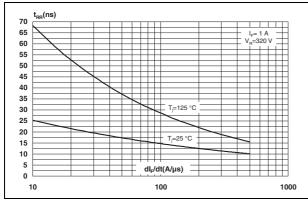
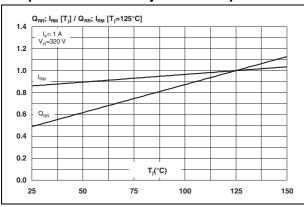
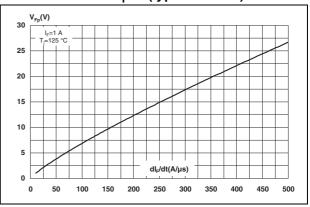


Figure 9. Relative variations of dynamic parameters versus junction temperature



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Figure 10. Transient peak forward voltage versus dl_F/dt (typical values)



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Figure 11. Forward recovery time versus dI_F/dt (typical values)

Figure 12. Thermal resistance junction to ambient versus copper surface under each lead

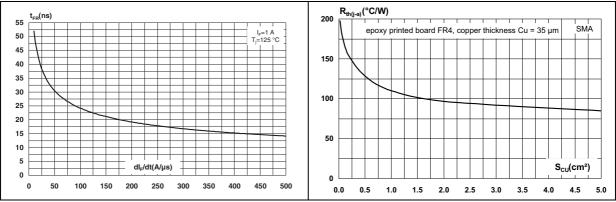
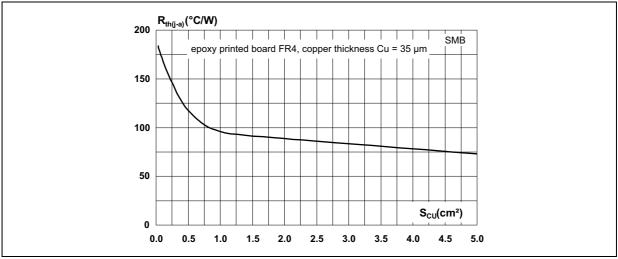


Figure 13. Thermal resistance junction to ambient versus copper surface under each lead



Package information STTH1R04-Y

Package information 2

- Epoxy meets UL94, V0
- Lead-free package
- Cooling method: by conduction (C)

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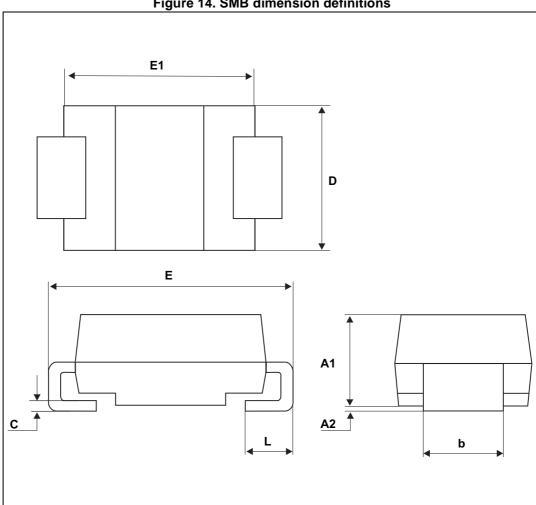
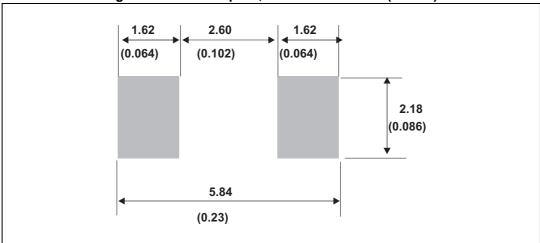


Figure 14. SMB dimension definitions

Table 6. SMB dimension values

	Dimensions					
Ref.		Millimeters	Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.
A1	1.90		2.45	0.075		0.096
A2	0.05		0.20	0.002		0.008
b	1.95		2.20	0.077		0.087
С	0.15		0.40	0.006		0.016
D	3.30		3.95	0.130		0.156
Е	5.10		5.60	0.201		0.220
E1	4.05		4.60	0.159		0.181
L	0.75		1.50	0.030		0.059

Figure 15. SMB footprint, dimensions in mm (inches)



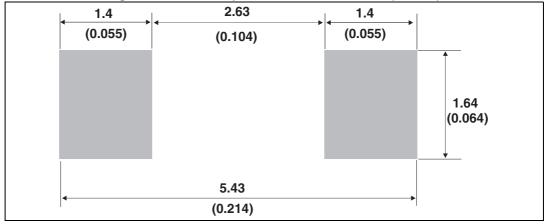
Package information STTH1R04-Y

Figure 16. SMA dimension definitions

Table 7. SMA dimension values

Table 11 clast amonoton values						
Dimensions						
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
A1	1.90		2.45	0.075		0.094
A2	0.05		0.20	0.002		0.008
b	1.25		1.65	0.049		0.065
С	0.15		0.40	0.006		0.016
D	2.25		2.90	0.089		0.114
E	4.80		5.35	0.189		0.211
E1	3.95		4.60	0.156		0.181
L	0.75		1.50	0.030		0.059

Figure 17. SMA footprint, dimensions in mm (inches)



3 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH1R04AY	HR4Y	SMA	0.068 g	5000	Tape and reel
STTH1R04UY	BR4Y	SMB	0.12 g	2500	Tape and reel

4 Revision history

Table 9. Document revision history

Date	Revision	Description of changes
09-Jul-2013	1	First issue

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